



## DFB + 10G EML 1550 nm TOSA-LC

### Description

A 1550 nm DFB laser packaged with a 10G External Absorption Modulator (EAM) to create an EML. This device offers a built-in a power a monitoring InGaAs photodiode and Peltier thermal electric cooler (TEC). The device comes in an 8 Pin TO-can LC receptacle. The device features a built-in optical isolator. An optional LC flange can be mounted to allow easy LC connector attachment.

### Features

- 3 mW Optical Power
- Built in monitor Photodiode
- Available wavelengths
  - 1550 nm
  - More coming soon
- 8 GHz Cutoff Frequency
- High power efficiency 90%
- Built in TEC
- Built in Isolator
- Up to 80 KM transmission



### Applications

- Telecommunications
- RF over Fiber (RFoF)



IMPORTANT NOTICE: more information on warranty, changes, rights, notices, and other information are presented at the back of this data sheet. If the back sheet is not present, refer to [www.nuphotonics.com](http://www.nuphotonics.com) for the company issued data sheet.

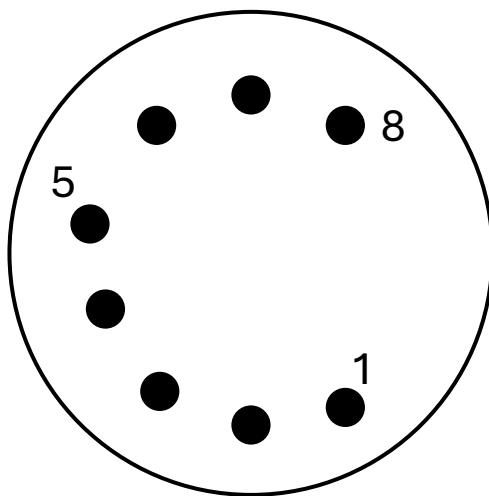
## Electro-Optical Characteristics (T = 25°C)

Parameter	Symbol	Condition	Min.	Typical	Max.	Unit
Forward Voltage (LD)	V <sub>f</sub>	Laser	-	1.2	2.0	V
Threshold Current (LD)	I <sub>th</sub>	Laser	-	10	-	mA
Spectral Width	Δλ	Laser	-	1	-	nm
Constant Optical Power	P <sub>cw</sub>	Laser	-	3	-	mW
Center Wavelength	λ <sub>c</sub>	T = 25°C	1540	-	1550	nm
Side-Mode Suppression	SMSR	CW, 90mA	30	-	-	dB
Monitor Current	I <sub>m</sub>	-	50	-	2000	μA
Bandwidth	BW	-	-	8	-	GHz
Optical Isolation	I <sub>iso</sub>	-	30	-	-	dB
Thermistor	R <sub>th</sub>	25°C	-	10	-	kΩ
Relative Intensity Noise	RIN	25°C	-	-	-130	dB/Hz
TEC	Q <sub>max</sub>	-	-	-	0.6	W
	I <sub>max</sub>	-	-	-	0.9	A
	V <sub>max</sub>	-	-1.2	-	1.2	V
	ΔT	-	-	40	-	K
	B Const	R <sub>th</sub>	-	3930	-	K
Laser Series Resistance	R	25°C	-	8	-	Ω
Modulator Voltage	V <sub>mod</sub>	25°C	-4	-	1	V

## Absolute Maximum Rating (T = 25°C)

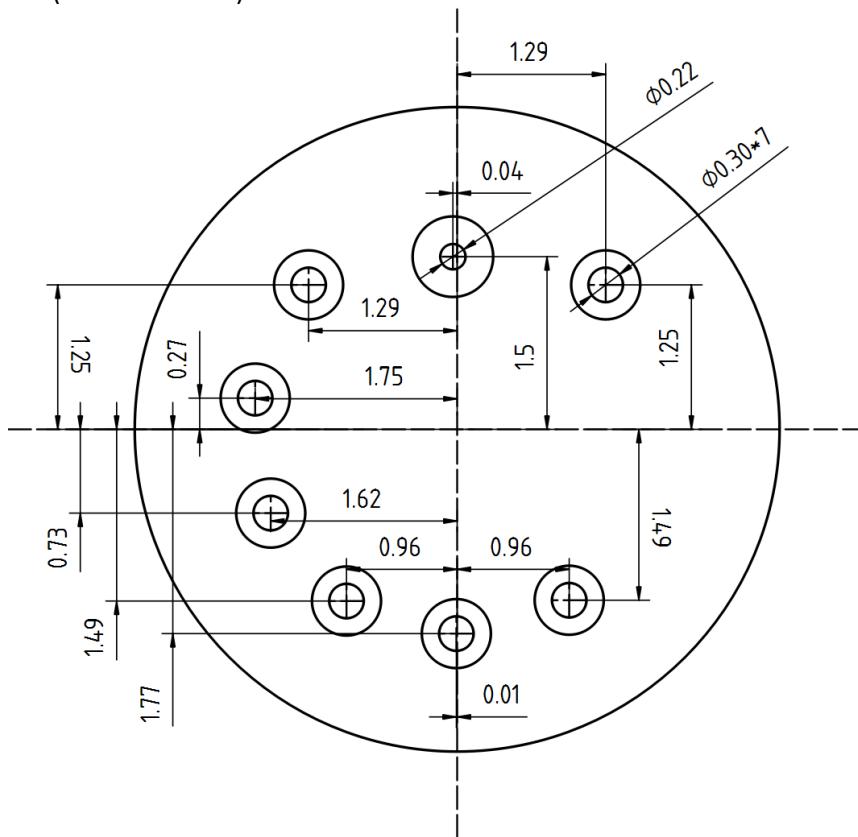
Parameter	Symbol	Condition	Min.	Max.	Unit
Reverse Voltage	V <sub>r</sub>	Laser	-	2	V
		Photodiode		10	
Forward Current	I <sub>F</sub>	Laser	-	140	mA
Reverse Current	I <sub>R</sub>	Photodiode	-	2	mA
TEC Current	I <sub>TEC</sub>	-	-	1.2	A
Storage Temperature	T <sub>stg</sub>	-	-25	90	°C
Storage Humidity	H <sub>stg</sub>	-	-	85	% r.H.
Operating Temperature	T <sub>op</sub>	-	-25	80	°C
Soldering Temperature	T <sub>st</sub>	60 sec	-	200	°C
ESD Susceptibility		HBM	100	-	V

## Device Pin Configuration

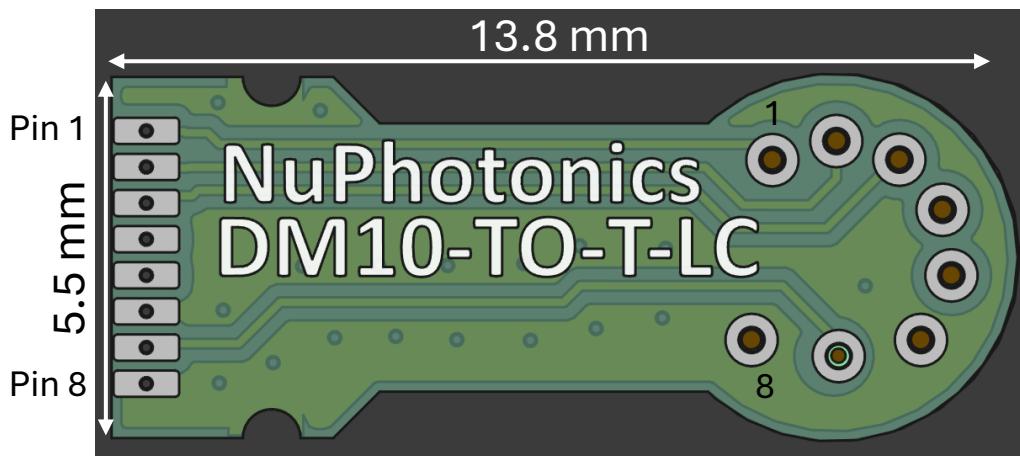


Pin #	Description:
1	Thermistor
2	Laser Anode (+)
3	Photodiode Anode (+)
4	TEC (-)
5	TEC (+)
6	GND
7	Modulator Bias + RFin
8	GND

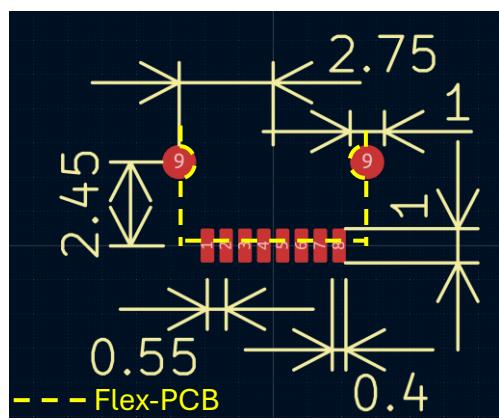




Flexible PCB (optional for mounting device horizontally)



Recommended Footprint

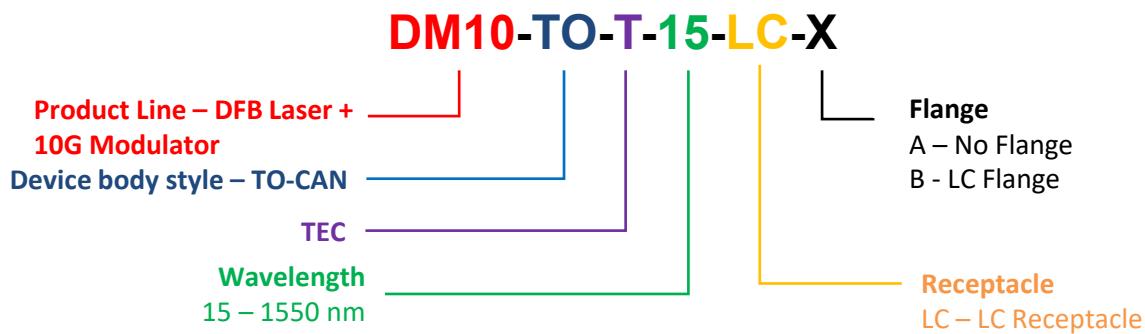


**Footprint note:**

Pin 9 should be tied to RF/DC ground. These pins offer mechanical support to the flexible PCB.

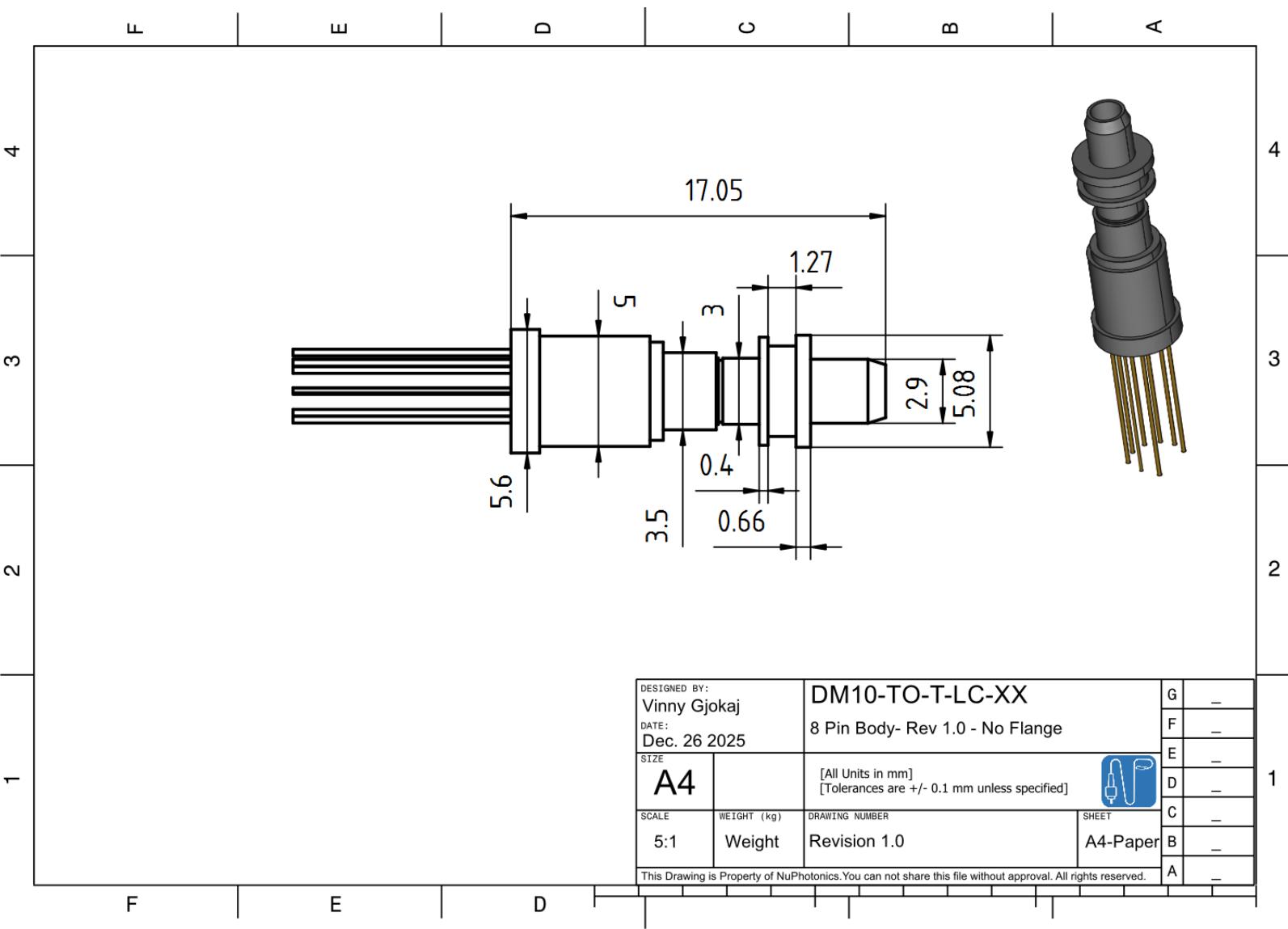


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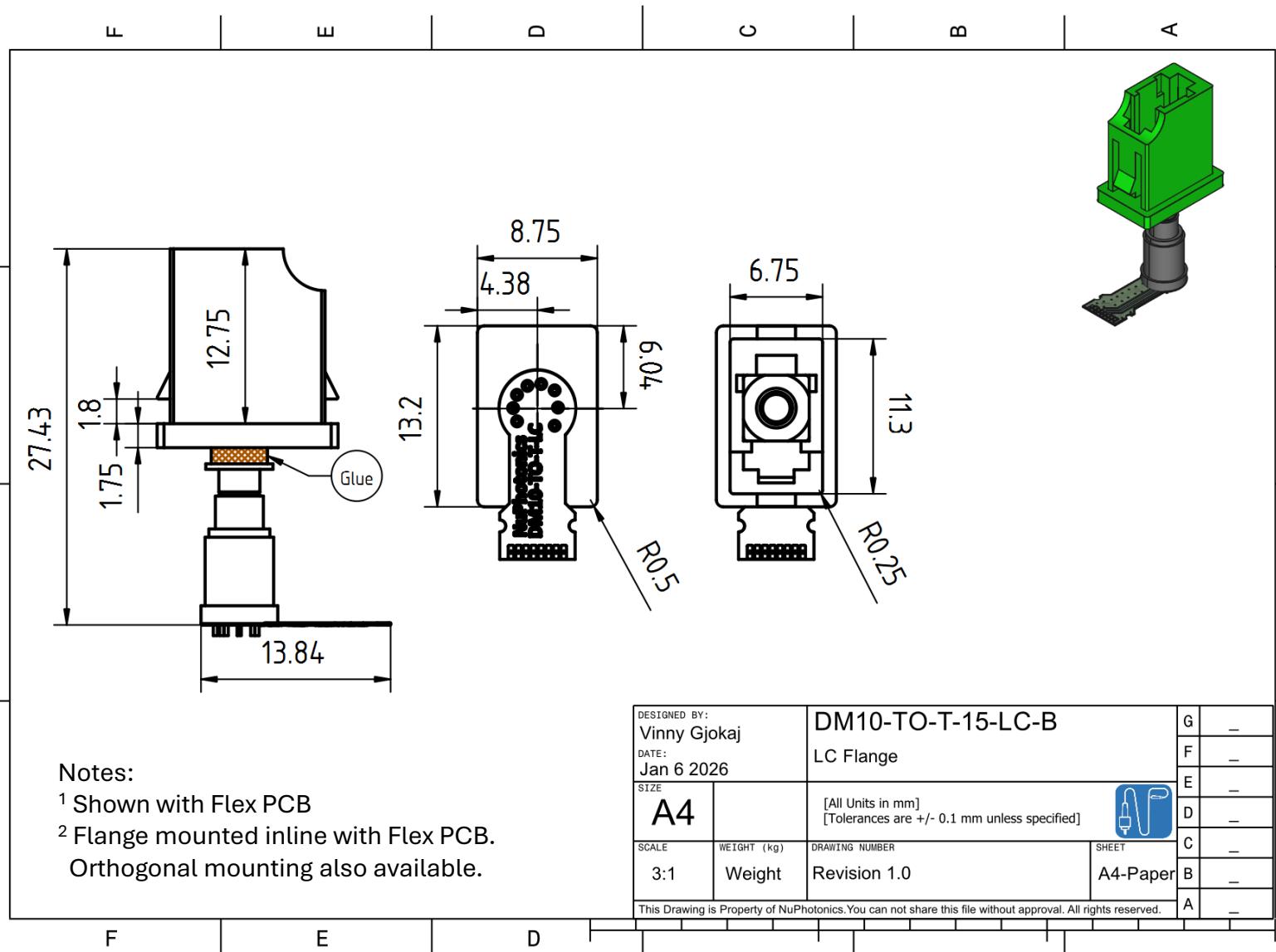


Example – DM10-TO-T-15-LC-B

1550 nm DFB + 10G Modulator TO-Can with TEC LC receptacle with LC flange.

**Mechanical Drawing**

## Mechanical Drawing (With Flange)



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Production Build: Customer ready devices. Small appearance changes may occur between devices.

Obsolete: Currently not supported.

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# Revision History

1.0 – December 2025 – Initial Release